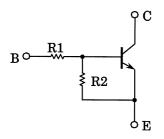
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

RN1107F,RN1108F,RN1109F

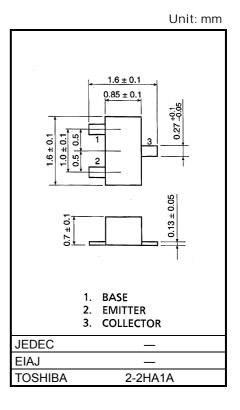
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors.
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2107F~2109F

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1107F	10	47
RN1108F	22	47
RN1109F	47	22



Maximum Ratings (Ta = 25°C)

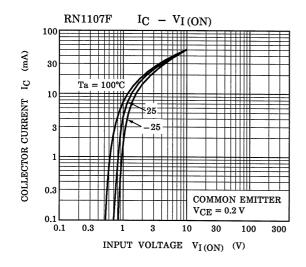
Characterist	Symbol	Rating	Unit		
Collector-base voltage	RN1107F~1109F	V_{CBO}	50	V	
Collector-emitter voltage	RN1107F~1109F	V_{CEO}	50	V	
	RN1107F		6	٧	
Emitter-base voltage	RN1108F	V_{EBO}	7		
	RN1109F		15		
Collector current	RN1107F~1109F	I _c	100	mA	
Collector power dissipation	RN1107F~1109F	Pc	100	mW	
Junction temperature	RN1107F~1109F	Tj	150	°C	
Storage temperature range	RN1107F~1109F	T _{stg}	-55~150	°C	

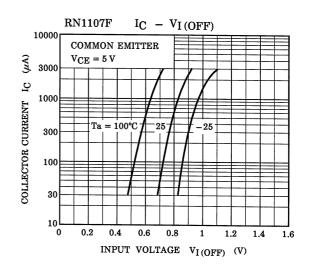


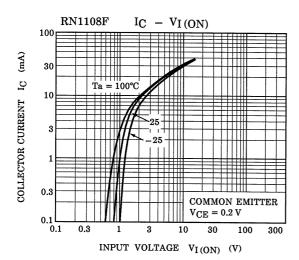
Electrical Characteristics (Ta = 25°C)

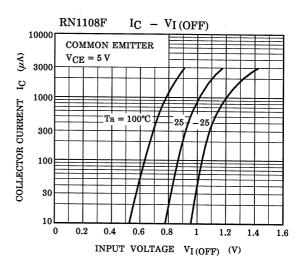
Character	ristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1107F~1109F	I _{CBO}	_	V _{CB} = 50V, I _E = 0	_	_	100	nA
		I _{CEO}	_	V _{CE} = 50V, I _B = 0	_	_	500	nA
	RN1107F		_	V _{EB} = 6V, I _C = 0	0.081	_	0.15	
Emitter cut-off current	RN1108F	I _{EBO}	_	V _{EB} = 7V, I _C = 0	0.078	_	0.145	mA
	RN1109F		_	V _{EB} = 15V, I _C = 0	0.167	_	0.311	
	RN1107F		_		80	_	_	
DC current gain	RN1108F	h _{FE}	_	V _{CE} = 5V, I _C = 10mA	80	_	_	_
	RN1109F	•	_		70	_	_	
Collector-emitter saturation voltage	RN1107F~1109F	V _{CE} (sat)	_	I _C = 5mA, I _B = 0.25mA	_	0.1	0.3	V
	RN1107F		_		0.7	_	1.8	
Input voltage (ON)	RN1108F	V _{I (ON)}	_	V _{CE} = 0.2V, I _C = 5mA	1.0	_	2.6	V
	RN1109F		_		2.2	_	5.8	
	RN1107F		_		0.5	_	1.0	
Input voltage (OFF)	RN1108F	V _{I (OFF)}	_	V _{CE} = 5V, I _C = 0.1mA	0.6	_	1.16	V
	RN1109F		_		1.5	_	2.6	
Translation frequency	RN1107F~1109F	f _T	_	V _{CE} =10V, I _C = 5mA	_	250	_	MHz
Collector output capacitance	RN1107F~1109F	C _{ob}	_	V _{CB} = 10V, I _E = 0, f = 1MHz	_	3	6	pF
	RN1107F		_		7	10	13	
Input Resistor	RN1108F	R1	_	_	15.4	22	28.6	kΩ
	RN1109F		_		32.9	47	61.1	
	RN1107F		_		0.191	0.213	0.232	
Resistor Ratio	RN1108F	R1/R2	_	_	0.421	0.468	0.515	_
	RN1109F		_		1.92	2.14	2.35	

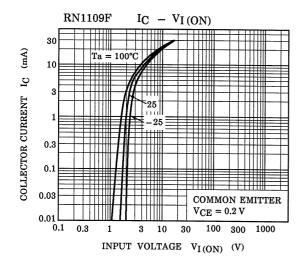
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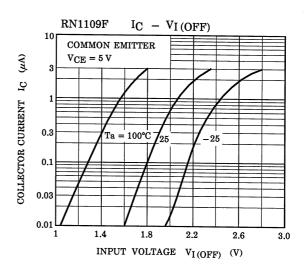


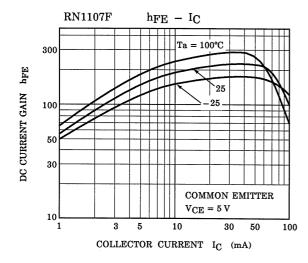


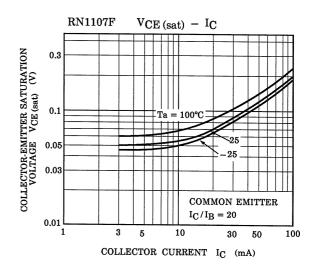


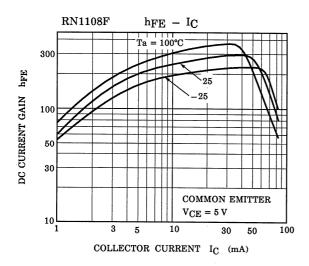


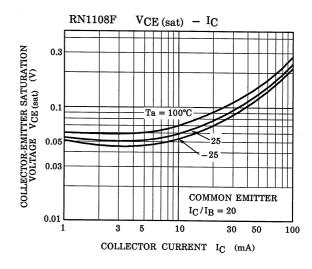


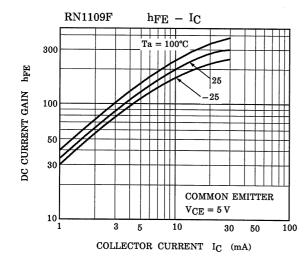


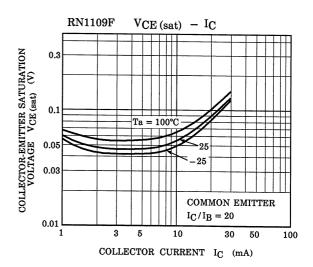












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Type Name	Marking
RN1107F	Type Name
RN1108F	Type Name
RN1109F	Type Name X J

2001-06-07

5

RESTRICTIONS ON PRODUCT USE

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